

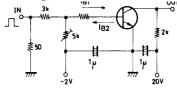
2SA1209/2SC2911

160V/140mA High-Voltage Switching and AF 100W Predriver Applications

Features

- · Adoption of FBET process.
- · High breakdown voltage.
- · Good linearity of hFE and small Cob.
- · Fast switching speed.

Switching Test Circuit



 I_C =10 I_B 1=-10 I_B 2=10mA (For PNP, the polarity is reversed) Unit (resistance : Ω , capacitance : F)

(): 2SA1209

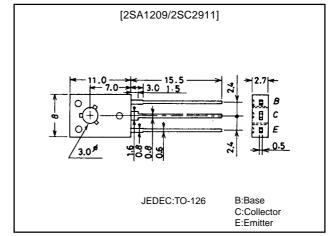
Specifications

Absolute Maximum Ratings at Ta = 25°C

Package Dimensions

unit:mm

2009A



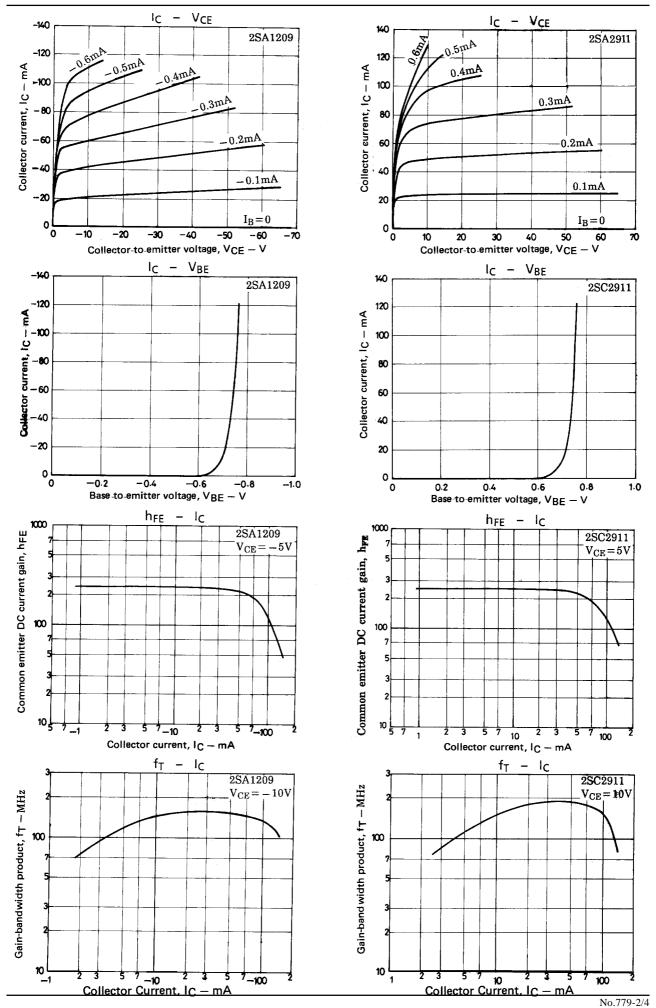
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		(-)180	V
Collector-to-Emitter Voltage	VCEO		(–)160	V
Emitter-to-Base Voltage	V _{EBO}		(-)5	V
Collector Current	Ic		(-)140	mA
Collector Current (Pulse)	I _{CP}		(–)200	mA
Collector Dissipation	PC		1	W
		Tc=25°C	10	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

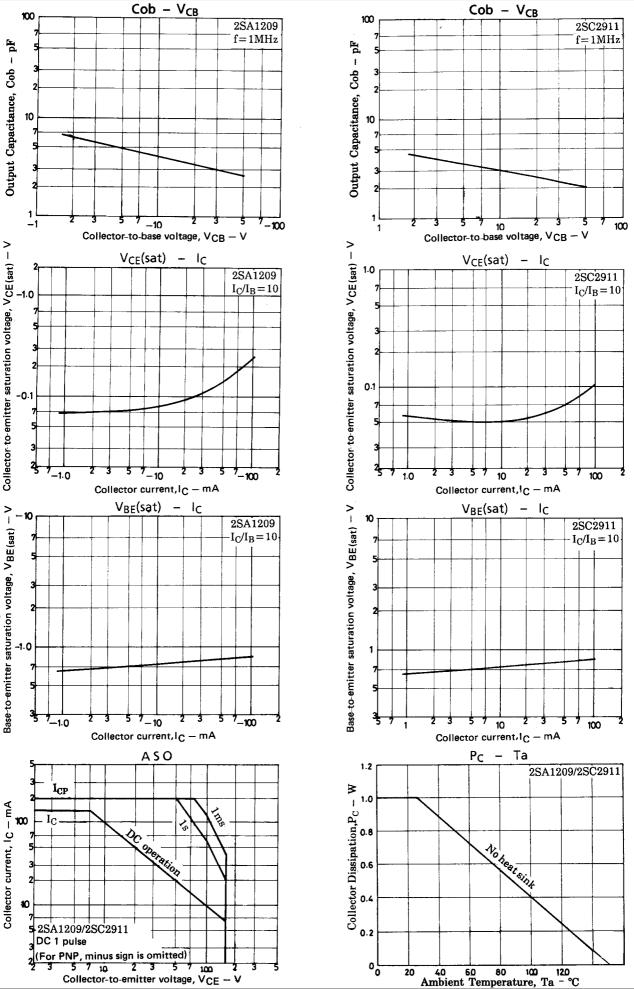
Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} =(-)80V, I _E =0			(-)0.1	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)4V, I _C =0			(–)0.1	μΑ
DC Current Gain	h _{FE}	V _{CE} =(-)5V, I _C =(-)10mA	100*		400*	
Gain-Bandwidth Product	f _T	V _{CE} =(-)10V, I _C =(-)10mA		150		MHz
Output Capacitance	C _{ob}	V _{CB} =(-)10V, f=1MHz		(4.0)3.0		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	I _C =(-)50mA, I _B =(-)5mA		0.07 (-0.14)	0.3 (-0.4)	V
Turn-ON Time	ton	See specified Test Circuit		0.1		μs
Fall Time	t _f	See specified Test Circuit		0.1		μs
Storage Time	t _{stq}	See specified Test Circuit		1.5		μs

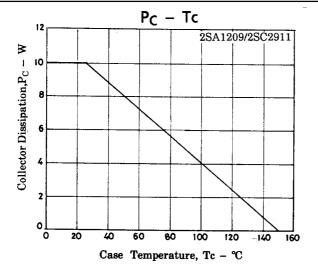
 $[\]overline{*: The 2SA1209/2SC2911}$ are classified by 10mA h_{FE} as follows :

100 R 200 140 S 280 200 T



2SA1209/2SC2911





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